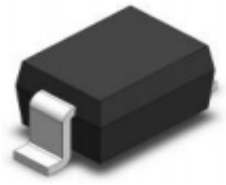
1-Line, Bi-directional, Transient Voltage Suppressors

Descriptions

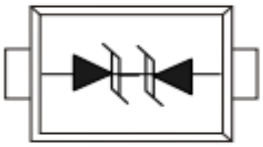
The ESD8A150TA is a bi-directional TVS (Transient Voltage Suppressor). It is specifically designed to protect sensitive electronic components that may be subjected to ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning. It is particularly well-suited for cellular phones, portable device, digital cameras, power supplies and many other portable applications because of its small package and low weight.

The ESD8A150TA may be used to provide ESD protection up to ±20kV air discharge ±20kV contact discharge according to IEC61000-4-2, and withstand peak pulse current up to 6.0A(8/20μs) according to IEC61000-4-5.

The ESD8A150TA is available in SOD-323 package. Standard products are Pb-free and Halogen-free.



SOD-323



Circuit diagram

Features

- Stand-off voltage: ±8VMax
- Transient protection for each line according to
  IEC61000-4-2 (ESD): ±20kV air discharge ±20kV contact discharge
  IEC61000-4-5 (surge): 6.0A(8/20μs)
- Solid-state silicon technology

Order information

Device	Package	Shipping	Mark
ESD8A150TA	SOD-323	3000/Tape&Reel	J

Applications

- Cell phone handsets and accessories
- Personal Digital Assistants (PDAs)
- Notebooks, Desktops, and Serves
- Portable Instrumentation
- Digital Cameras
- MID/CAR DVD/MP3/MP4/PMP Players

Absolute maximum ratings

Parameter	Symbol	Rating	Unit
Peak pulse power (t_p = 8/20μs)	P_{pk}	185	W
Peak pulse current (t_p = 8/20μs)	I_{PP}	6.0	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	±20	kV
ESD according to IEC61000-4-2 contact discharge		±20	
Operation junction temperature	T_J	-55~150	°C
Lead temperature	T_L	260	°C
Storage temperature	T_{STG}	-55~150	°C

Electrical characteristics (TA=25°C ,unless otherwise noted)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				±8.0	V
Reverse leakage current	I_R	V_{RWM} = 8.0V			1.0	μA
Reveres breakdown voltage	V_{BR}	I_T=1mA	8.5			V
Clamping voltage	V_C	Ipp=1A tp=8/20us			12.5	V
		Ipp=6.0Atp=8/20us			18.5	V
Junction capacitance	C_J	V_R = 0V, f = 1MHz		10.0	20.0	pF

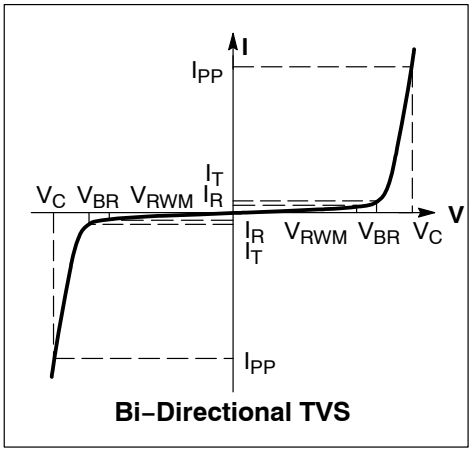
Electrical performance curve

V_C: Maximum clamping voltage

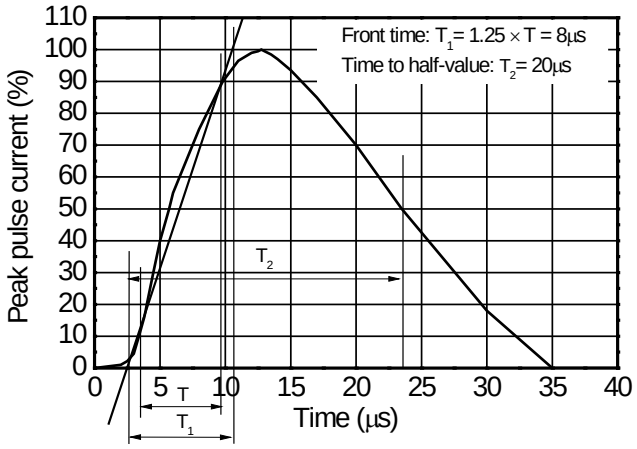
V_{br}: Reverse breakdown voltage

V_{RWM}: Working voltage

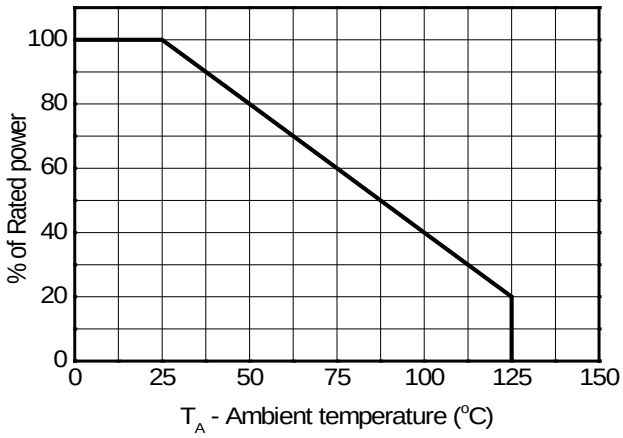
I_{PP}: Maximum peak current



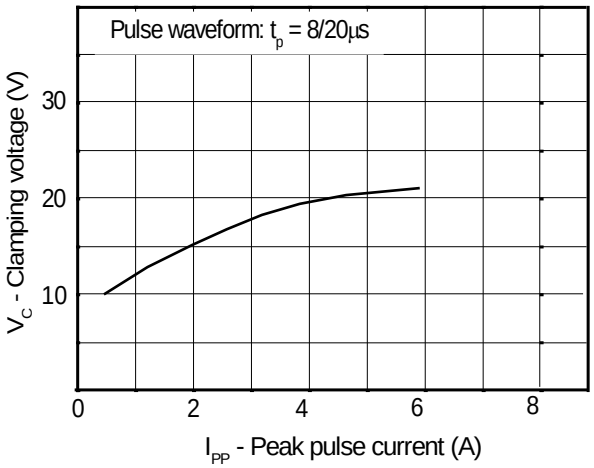
Bi-Directional TVS



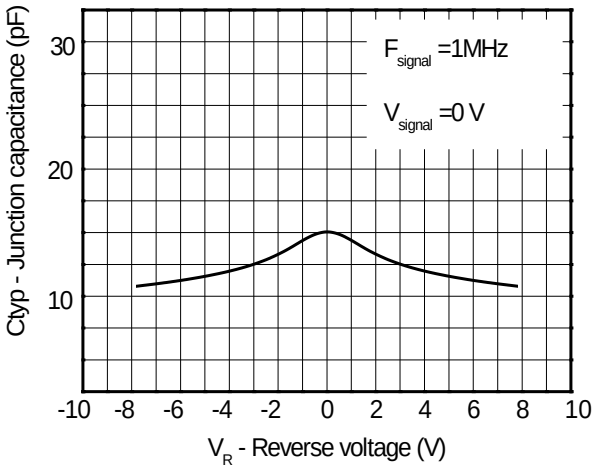
8/20μs waveform per IEC61000-4-5



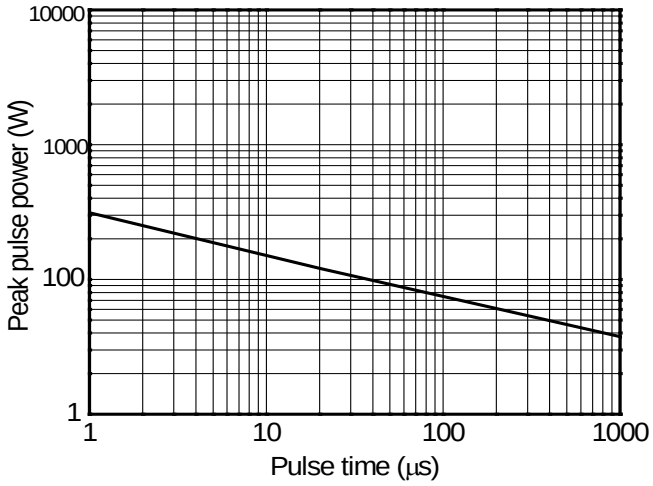
Power derating vs. Ambient temperature



Clamping voltage vs. Peak pulse current

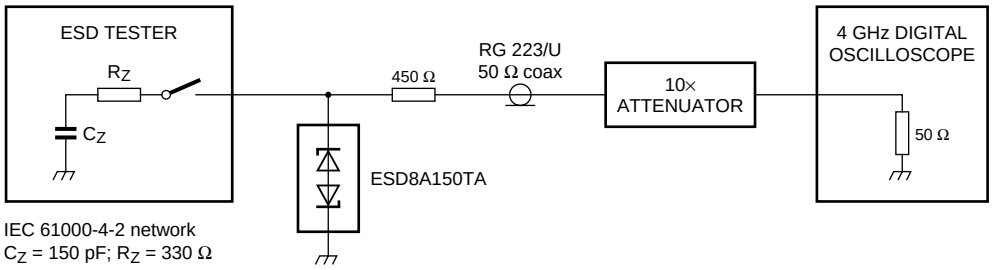


Capacitance vs. Reveres voltage

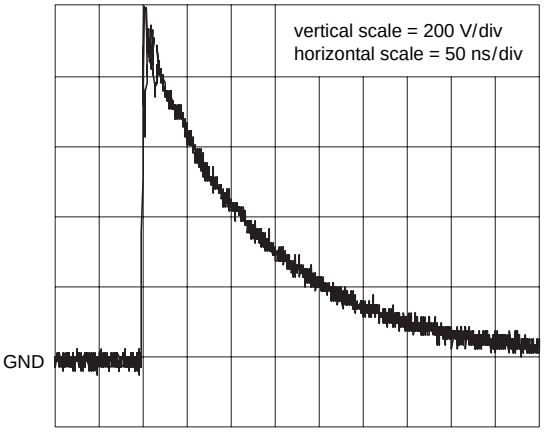


Non-repetitive peak pulse power vs. Pulse time

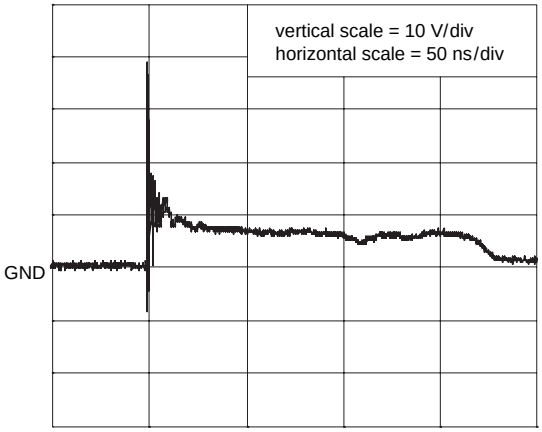
ESD clamping test setup and waveforms



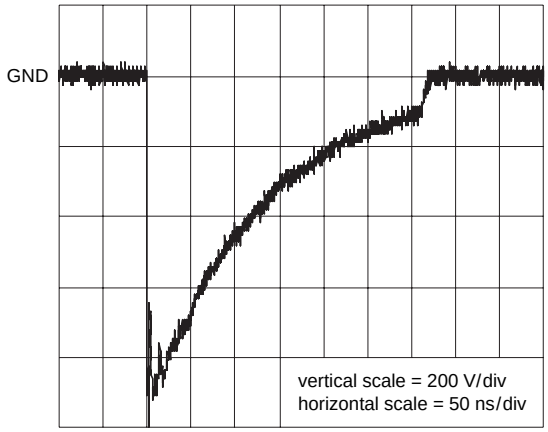
IEC 61000-4-2 network
C_Z = 150 pF; R_Z = 330 Ω



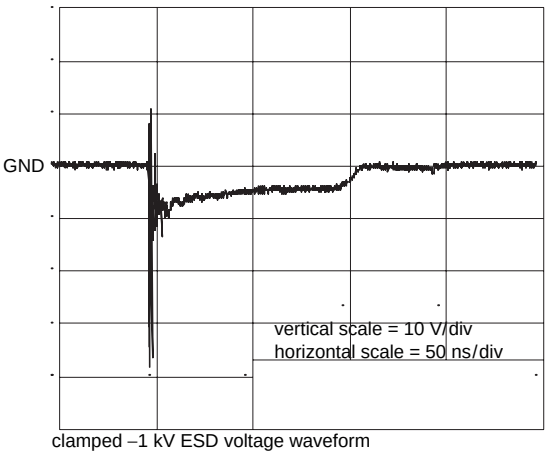
unclamped +1 kV ESD voltage waveform
(IEC61000-4-2 network)



clamped +1 kV ESD voltage waveform
(IEC61000-4-2 network)

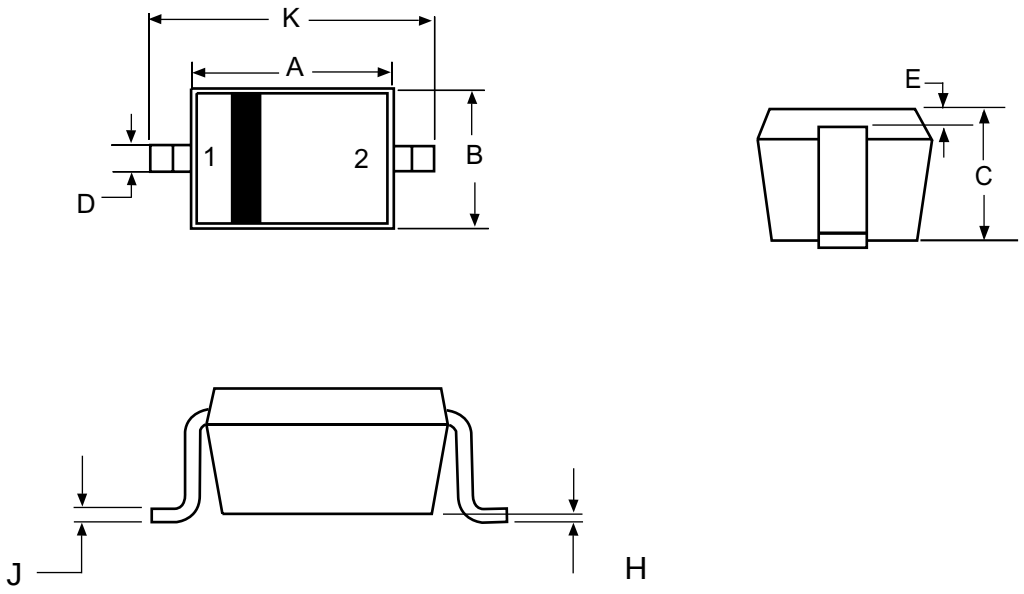


unclamped –1 kV ESD voltage waveform
(IEC61000-4-2 network)



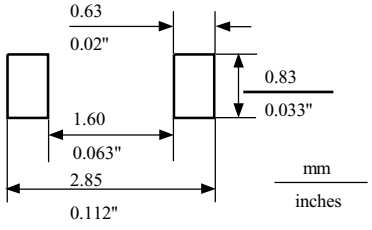
clamped –1 kV ESD voltage waveform
(IEC61000-4-2 network)

Package outline dimensions **SOD-323**



Symbol	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	1.60	1.80	0.063	0.071
B	1.15	1.35	0.045	0.053
C	0.80	1.00	0.031	0.039
D	0.25	0.40	0.010	0.016
E	0.15 REF		0.006 REF	
H	0.00	0.10	0.000	0.004
J	0.089	0.177	0.0035	0.0070
K	2.30	2.70	0.091	0.106

Recommend land pattern (Unit: mm)



Note: This land pattern is for your reference only. Actual pad layouts may vary depending on application.